0.008(0.203)Max.



SCHOTTKY DIODES

FEATURES

Metal silicon junction, majority carrier conduction

Low power loss, high efficiency

The plastic package carries Underwriters Laboratory flammability

Classification 94V-0

High forward surge current capability

Built-in strain relief, ideal for automated placement

MECHANICAL DATA

SMA (DO-214AC) molded plastic

Polarity: Color band denotes cathode end

0.067(1.70) 0.052(1.32) 0.17 (4.50) 0.157(3.99) 0.012(0.305) 0.005(0.13)

SS22---SS2200

Dimensions in inches and (millimeters)
DO-214AC (SMA)

0.209(5.31) 0.185(4.70)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

MDD Catalog Number	SYMBOLS	SS22	SS23	SS24	SS25	SS26	SS28	SS210	SS2150	SS2200	UNITS
Maximum repetitive peak reverse voltage	VRRM	20	30	40	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	VRMS	14	21	28	35	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	VDC	20	30	40	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at TL(see fig.1)	l(AV)	2.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50.0									Amps
Maximum instantaneous forward voltage at 2.0A	VF	0.55			0.	70	0 0.85			0.95	Volts
Maximum DC reverse current Ta=25℃	IR	0.5 0.2 10.0 5.0 2.0								mA	
at rated DC blocking voltage Ta=100°C		10.0				-		5.0	2.	.0	
Typical junction capacitance (NOTE 1)	Cı	220				180				pF	
Typical thermal resistance (NOTE 2)	RθJA	75.0								°C/W	
Operating junction temperature range	TJ,	-50 to +125				-50 to +150				°C	
Storage temperature range	Тѕтс	-50 to +150									°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas



SS22---SS2200 Typical Characteristics











